

Ultra-small 40 m Ω / 1.0 A Dual Load Switch

General Description

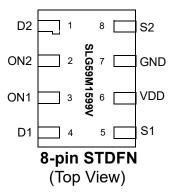
The SLG59M1599V is designed for load switching applications. The part comes with two 40 m Ω 1.0 A rated MOSFETs, each controlled by an ON control pin. Each MOSFET's ramp rate is adjustable depending on the input current level of the ON pin.

The product is packaged in an ultra-small 1.6 x 1.0 mm package.

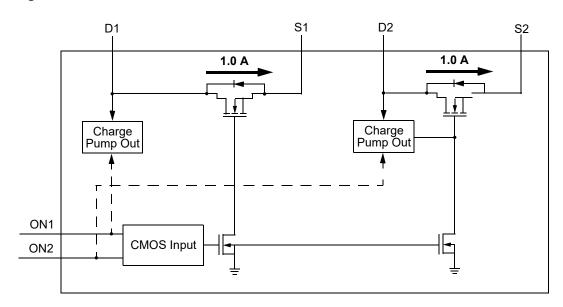
Features

- Two 40 m Ω 1.0 A MOSFETs
- · Two integrated VGS Charge Pumps
- User selectable ramp rate with external resistor
- · Protected by thermal shutdown
- Pb-Free / Halogen-Free / RoHS compliant
- STDFN 8L, 1.6 x 1.0 mm

Pin Configuration



Block Diagram





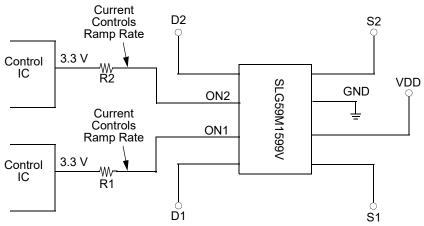
Pin Description

Pin#	Pin Name	Туре	Pin Description
1	D2	MOSFET	Drain of Power MOSFET1
2	ON2	Input	Turns on MOSFET1. Configurable slew rate control depending on input current.
3	ON1	Input	Turns on MOSFET2. Configurable slew rate control depending on input current.
4	D1	MOSFET	Drain of Power MOSFET2
5	S1	MOSFET	Source of Power MOSFET2
6	VDD	PWR	Power Supply
7	GND	GND	Ground
8	S2	MOSFET	Source of Power MOSFET1

Ordering Information

Part Number	Туре	Production Flow
SLG59M1599V	STDFN 8L	Industrial, -40 °C to 85 °C
SLG59M1599VTR	STDFN 8L (Tape and Reel)	Industrial, -40 °C to 85 °C

Application Diagram



000-0059M1599-103 Page 2 of 9



Absolute Maximum Ratings

Parameter	Description	Conditions	Min.	Тур.	Max.	Unit
V_{DD}	Power Supply				6	V
T _S	Storage Temperature		-65		150	°C
ESD _{HBM}	ESD Protection	Human Body Model	2000			V
ESD _{CDM}	ESD Protection	Charged Device Model	1000			V
MSL	Moisture Sensitivity Level			,	1	
$\theta_{\sf JA}$	Thermal Resistance,	1 x 1.6mm STDFN; Determined using 1 in ² , 1 oz. copper pads under each Dx and Sx terminal and FR4 pcb material		72		°C/W
W _{DIS}	Package Power Dissipation				0.4	W
MOSFET IDS _{PK}	Peak Current from Drain to Source	For no more than 1 ms with 1% duty cycle		1	1.5	Α

Note: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Electrical Characteristics

 $T_A = -40 \, ^{\circ}\text{C}$ to 85 $^{\circ}\text{C}$ (unless otherwise stated)

Parameter	Description	Conditions	Min.	Тур.	Max.	Unit
V_{DD}	Power Supply	Pin 6	2.5		5.5	V
V _{D1}	Drain Voltage of MOS1	Pin 4	0.85		V_{DD}	V
V _{D2}	Drain Voltage of MOS2	Pin 1	0.85		V_{DD}	V
	Power Supply Current (PIN 6)	when OFF		0.1	1	μΑ
I _{DD}	Power Supply Current (Filt 0)	when ON, No load		35	50	μΑ
	0	T _A 25°C MOSFET[1:2]		40	50	mΩ
RDS _{ON}	Static Drain to Source ON Resistance	T _A 70°C MOSFET[1:2]		50	55	mΩ
		T _A 85°C MOSFET[1:2]		55	65	mΩ
IDS	Operating Current	V _D = 2.5 V to 5.5 V			1.0	Α
T _{Delay_ON}	ON pin Delay Time	50% ON to Ramp Begin Input Current (PIN2, PIN3) = 20 μ A, V _{DD} = V _D = 5 V, Source_Cap = 10 μ F, R _L = 20 Ω		2.4	4.0	ms
		50% ON to 90% V _S	Co	Configurable ¹		
T _{Total_ON}	Total Turn On Time	Example: Input Current (PIN2, PIN3) = 20 μ A, V_{DD} = V_{D} = 5 V, Source_Cap = 10 μ F, R_{L} = 20 Ω		11.7		ms
		10% V _S to 90% V _S	Co	nfigurable	e 1	V/ms
T _{SLEWRATE}	Slew Rate	Example: Input Current (PIN2, PIN3) = 20 μ A, V_{DD} = V_{D} = 5 V, Source_Cap = 10 μ F, R_{L} = 20 Ω		0.56		V/ms
ON_V _{REF}	ON Pin Reference Voltage ²		0.99	1.05	1.10	V
ON_V _{IH_INI}	Initial Turn On Voltage	Internal Charge Pump ON	1.2		V_{DD}	V
ON_V _{IL}	Low Input Voltage on ON pin	Internal Charge Pump OFF	-0.3	0	0.3	V
ON_R	Input Impedance on ON pin		100			MΩ
THERMON	Thermal shutoff turn-on temperature			125		°C
THERM _{OFF}	Thermal shutoff turn-off temperature			100		°C
THERM _{TIME}	Thermal shutoff time				1	ms

000-0059M1599-103 Page 3 of 9



Electrical Characteristics (continued)

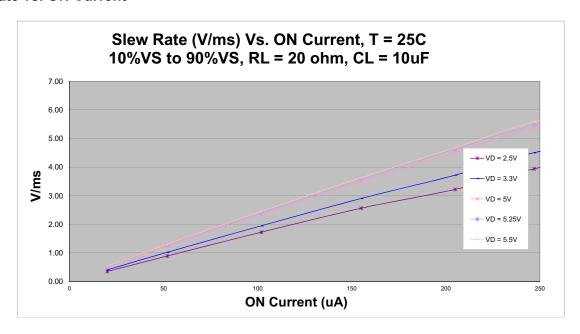
 $T_A = -40 \, ^{\circ}\text{C}$ to 85 $^{\circ}\text{C}$ (unless otherwise stated)

Parameter	Description Conditions		Min.	Тур.	Max.	Unit
T _{OFF_Delay}	OFF Delay Time	50% ON to V_S Fall, V_D = 5 V, R_L = 20 Ω		55	70	μs
T _{FALL}	V _S Fall Time	90% V_S to 10% V_S , V_D = 5 V , R_L = 20 Ω		32		μs

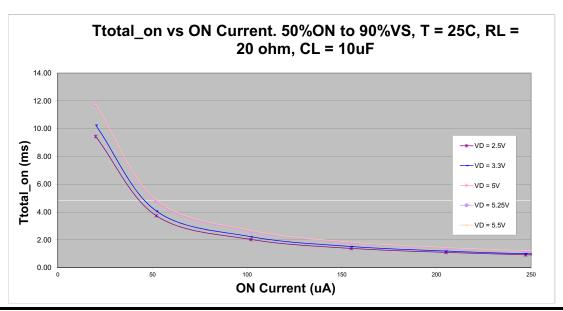
Notes:

- 1. Refer to table for configuration details.
- 2. Voltage before ON pin resistor needs to be higher than 1.2 V to generate required $I_{\mbox{ON}}$

Slew Rate vs. ON Current



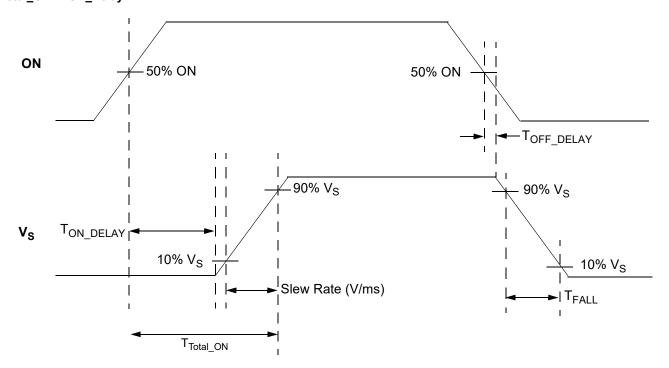
T_{Total_ON} vs. On Current



000-0059M1599-103 Page 4 of 9



$\rm T_{Total_ON}, \rm T_{ON_Delay}$ and Slew Rate Measurement



Adjustable Ramp Rate vs. ON Pin Current (5.5 V, 25 °C)

I_ON	T _{SLEW} (typ)
20 μΑ	0.56 V/ms
50 μΑ	1.34 V/ms
100 μΑ	2.53 V/ms
150 μΑ	3.71 V/ms
200 μΑ	4.68 V/ms
250 μΑ	5.63 V/ms

Adjustable Slew Rate (ON2 Pin 2 and ON1 Pin3)

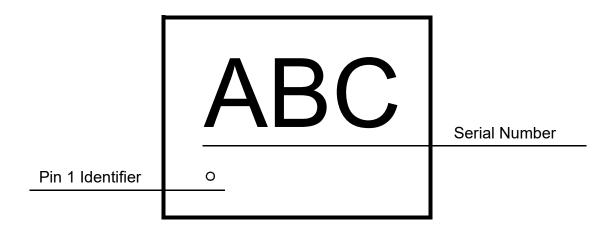
SLG59M1599V has a built in configurable slew control feature. The configurable slew control uses current detection method on ON1/ON2. When ON voltage rise above ON_VIH_INI (1.2 V typical), the slew control circuit will measure the current flowing into ON1/ON2. Based on the current flowing into ON1/ON2, different slew rates will be selected by the internal control circuit. See I_ON vs. Tslew table. The slew rate is configurable by selecting a different R1/R2 resistor value as shown on application diagram. Calculating the R1/R2 value depends on both the desired slew rate, and the VOH level of the device driving the ON1/ON2 pin.

ON_Current = (GPIO_VOH - ON_VREF (1.05 V typical)) / R

000-0059M1599-103 Page 5 of 9



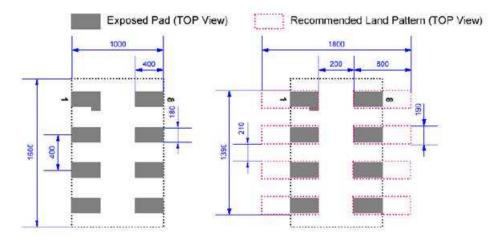
Package Top Marking System Definition



000-0059M1599-103 Page 6 of 9



SLG59M1599V Layout Suggestion



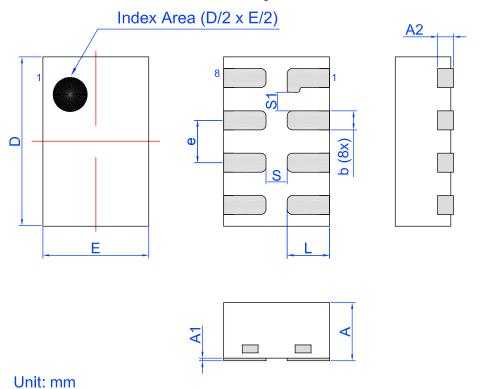
Package Drawing and Dimensions

Symbol

Min

0.50

8 Lead STDFN Package 1.0 x 1.6 mm



A1 E 0.95 0.005 0.060 1.00 1.05 **A2** 0.10 0.15 0.20 L 0.35 0.40 0.45 S b 0.13 0.18 0.23 0.2 REF **S1** 0.175 REF 0.40 BSC

Max

0.60

Nom.

0.55

000-0059M1599-103 Page 7 of 9

Symbol

D

Min

1.55

Nom.

1.60

Max

1.65

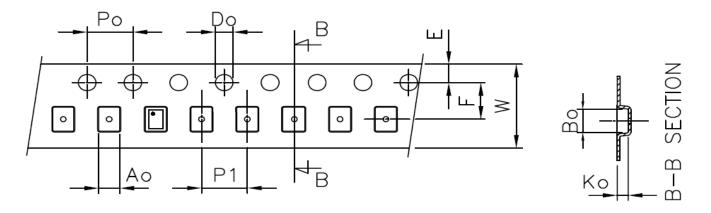


Tape and Reel Specifications

Bookogo	# of	Nominal	Max Units		Reel & Leader (min)		Trailer (min)		Tape	Part	
Package Type	# OI Pins	Package Size [mm]	per Reel	per Box	Hub Size [mm]	Pockets	Length [mm]	Pockets	Length [mm]	Width [mm]	Pitch [mm]
STDFN 8L 1x1.6mm 0.4P Green		1.0 x 1.6 x 0.55	3,000	3,000	178 / 60	100	400	100	400	8	4

Carrier Tape Drawing and Dimensions

Package Type	PocketBTM Length	PocketBTM Width	Pocket Depth	Index Hole Pitch	Pocket Pitch	Index Hole Diameter	Index Hole to Tape Edge		Tape Width
	A0	В0	K0	P0	P1	D0	E	F	W
STDFN 8L 1x1.6mm 0.4P Green	1.12	1.72	0.7	4	4	1.55	1.75	3.5	8



Recommended Reflow Soldering Profile

Please see IPC/JEDEC J-STD-020: latest revision for reflow profile based on package volume of 0.88 mm³ (nominal). More information can be found at www.jedec.org.

000-0059M1599-103 Page 8 of 9





Revision History

Date	Version	Change
2/4/2022	1.03	Updated Company name and logo Fixed typos
2/4/2022	1.02	Updated Company name and logo Fixed typos
11/20/2015	1.01	Added ESD _{CDM} , MSL, and θ_{JA} specs

000-0059M1599-103 Page 9 of 9

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